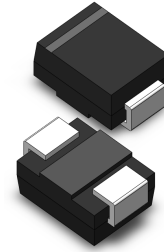


## SURFACE MOUNT SCHOTTKY BARRIER DIODES

**VOLTAGE RANGE: 20 - 100V**

**CURRENT: 2.0 A**

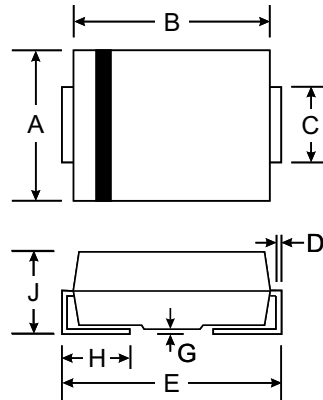


### Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction

### Mechanical Data

- Case: SMB/DO-214AA, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)



SMB(DO-214AA)		
Dim	Min	Max
A	3.30	3.94
B	4.06	4.70
C	1.91	2.21
D	0.15	0.31
E	5.00	5.59
G	0.10	0.20
H	0.76	1.52
J	2.00	2.62
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SS22B	SS23B	SS24B	SS25B	SS26B	SS28B	SS210B	Unit
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	V
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	V
Maximum average forward rectified current at T <sub>L</sub> (see fig.1)	I <sub>(AV)</sub>	2.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	50.0							A
Maximum instantaneous forward voltage at 2.0A	V <sub>F</sub>	0.50		0.70		0.85		V	
Maximum DC reverse current at rated DC blocking voltage <small>T<sub>A</sub>=25°C</small> <small>T<sub>A</sub>=100°C</small>	I <sub>R</sub>	0.5							mA
		20		10					
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	220		180		pF			
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>	75.0							°C/W
Operating junction temperature range	T <sub>J</sub>	-65 to +125			-65 to +150			°C	
Storage temperature range	T <sub>STG</sub>	-65 to +150							°C

**Note:**1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
2.P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

FIG. 1- FORWARD CURRENT DERATING CURVE

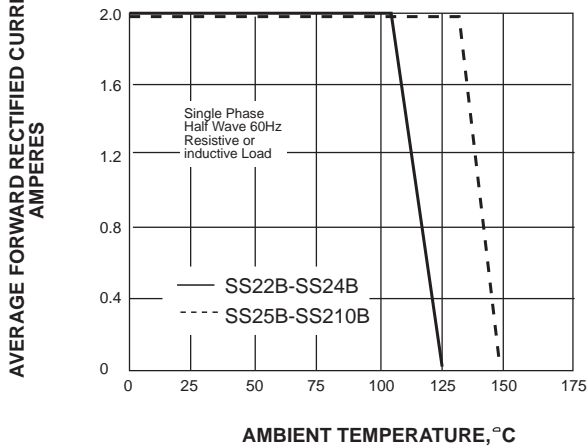


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

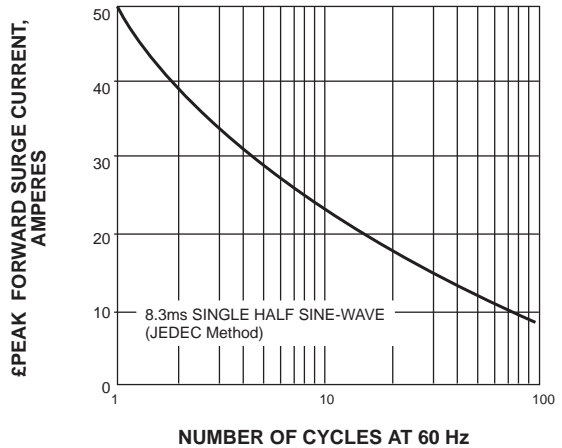


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

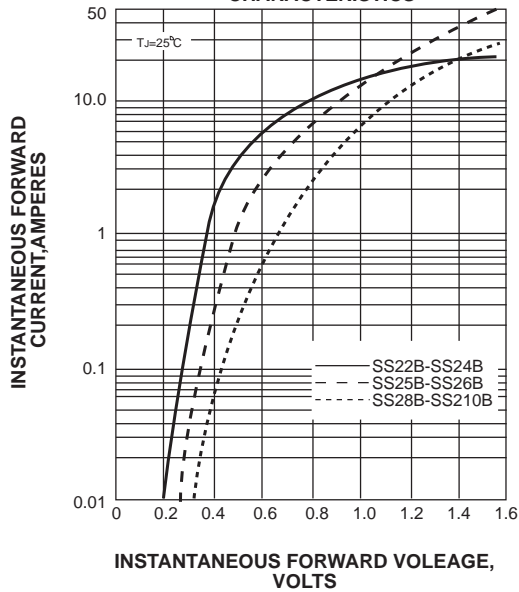


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

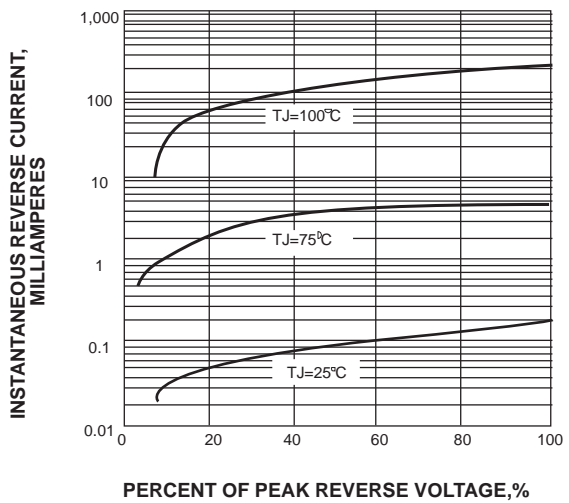


FIG. 5-TYPICAL JUNCTION CAPACITANCE

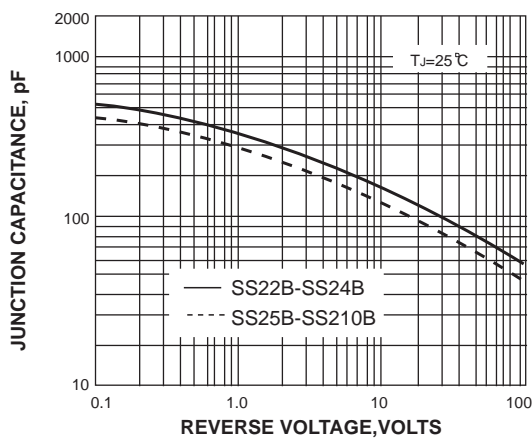
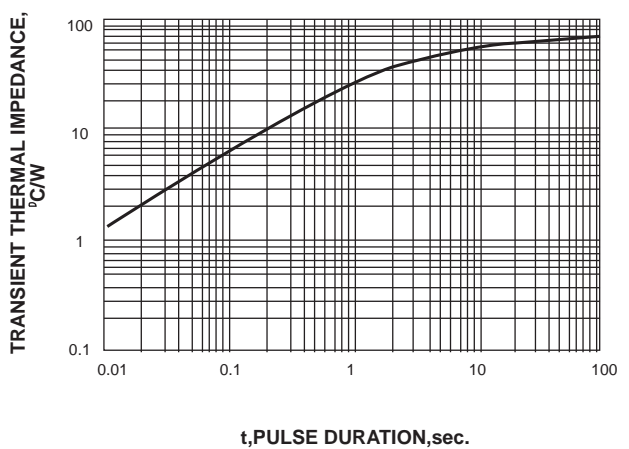


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Schottky Diodes & Rectifiers](#) category:*

*Click to view products by [SLKORMICRO](#) manufacturer:*

Other Similar products are found below :

[MA4E2039](#) [MA4E2508M-1112](#) [MBR1545CT](#) [MMBD301M3T5G](#) [RB160M-50TR](#) [D83C](#) [BAS16E6433HTMA1](#) [BAT 54-02LRH E6327](#)  
[NRVBAF360T3G](#) [NSR05F40QNXT5G](#) [NTE555](#) [JANS1N6640](#) [SK310-T](#) [SK34B-TP](#) [SS3003CH-TL-E](#) [GA01SHT18](#)  
[CRS10I30A\(TE85L,QM](#) [MA4E2501L-1290](#) [MBRA140TRPBF](#) [MBRB30H30CT-1G](#) [BAT 15-04R E6152](#) [JANTX1N5712-1](#) [DMJ3940-000](#)  
[SB007-03C-TB-E](#) [SK33B-TP](#) [NRVBB20100CTT4G](#) [NRVBM120LT1G](#) [NTSB30U100CT-1G](#) [VS-6CWQ10FNHM3](#) [CRG04\(T5L,TEMQ\)](#)  
[ACDBA1100LR-HF](#) [ACDBA1200-HF](#) [ACDBA240-HF](#) [ACDBA3100-HF](#) [CDBQC0530L-HF](#) [CDBQC0240LR-HF](#) [ACDBA260LR-HF](#)  
[ACDBA1100-HF](#) [MA4E2502L-1246](#) [10BQ015-M3/5BT](#) [NRVBM120ET1G](#) [CRS08TE85LQM](#) [PMAD1108-LF](#) [B120Q-13-F](#) [1N5819T-G](#)  
[B0530WSQ-7-F](#) [PDS1040Q-13](#) [B160BQ-13-F](#) [SDM05U20CSP-7](#) [B140S1F-7](#)